Day: Wednesday



PALM INTRANET

Date: 4/12/2006 Time: 07:16:50

Inventor Name Search Result

Your Search was:

Last Name = SATOH First Name = SHINICHI

Application#	Patent#	Status	Date Filed	Title	Invent Name
06454273	4478376	150	1	METHOD OF WINDING MAGNETIC RECORDING TAPE	SATOI SHINI
06694322	Not Issued	166	01/24/1985	SEMICONDUCTOR INTEGRATED CIRCUIT DEVICE	SATOI SHINI
06849759	4680598	150	04/08/1986	CHROMOGENIC MATERIALS EMPLOYING FLUORAN COMPOUNDS	SATOI SHINI
06904119	<u>4753158</u>	150	09/05/1986	PILOT HYDRAULIC SYSTEM FOR OPERATING DIRECTIONAL CONTROL VALVE	SATOI SHINI
<u>06918472</u>	4687862	150	10/14/1986	FLUORAN COMPOUNDS	SATOI SHINI
<u>07047607</u>	Not Issued	166	05/01/1987	SEMICONDUCTOR INTEGRATED CIRCUIT DEVICE	SATO) SHINI
07067178	Not Issued	161	06/29/1987	ROOM TEMPERATURE CURABLE ORGANOPOLYSILOXANE COMPOSITION	SATOI SHINI
07079050	Not Issued	161	07/29/1987	ORGANIC SILICON COMPOUNDS	SATOI SHINI
07092000	4801725	150	09/02/1987	ORGANOSILICON COMPOUND	SATOI SHINI
07094647	Not Issued	166	09/09/1987	SEMICONDUCTOR MEMORY CELLS HAVING COMMON CONTACT HOLE	SATOI SHINI
07101427	4875337	150	09/28/1987	CONSTRUCTION MACHINE DUAL-PUMP HYDRAULIC CIRCUIT WITH PILOTED ARM-BOOM CYLINDER SUPPLY RRIORITY SWITCHING VALVES	SATOI SHINI
<u>07143400</u>	4905068	150		SEMICONDUCTOR DEVICE HAVING INTERCONNECTION LAYERS OF T- SHAPE CROSS SECTION	SATOI SHINI
<u>07150166</u>	4892895	150		ULTRAVIOLET-CURABLE ORGANOPOLYSILOXANE	SATOI SHINI

				COMPOSITION	
07170028	4887137	250	03/04/1988	SEMICONDUCTOR MEMORY DEVICE	SATOI SHINI
07196011	4832082	150	04/22/1988	HYDRAULIC PILOT OPERATED DIRECTIONAL CONTROL VALVE	SATOI SHINI
07216023	4861908	150	07/07/1988	ORGANOSILICON COMPOUND	SATOI SHINI
07216163	4960847	150	07/07/1988	ROOM TEMPERATURE VULCANIZABLE ORGANOPOLYSILOXANE COMPOSITION	SATOI SHINI
07221509	4858649	150	04/29/1988	VALVE APPARATUS	SATOI SHINI
07232551	Not Issued	166	08/15/1988	SEMICONDUCTOR INTEGRATED CIRCUIT DEVICE	SATOI SHINI
<u>07242116</u>	5089863	150	09/08/1988	FIELD EFFECT TRANSISTOR WITH T- SHAPED GATE ELECTRODE	SATOI SHINI
07261022	5027173	150	10/20/1988	SEMICONDUCTOR MEMORY DEVICE WITH TWO SEPARATE GATES PER BLOCK	SATOI SHINI
07317721	Not Issued	168	03/02/1989	PHOTOCURABLE ORGANOPOLYSILOXANE COMPOSITION	SATOI SHINI
07337723	5014110	150	04/12/1989	WIRING STRUCTURES FOR SEMICONDUCTOR MEMORY DEVICE	SATOI SHINI
<u>07358495</u>	4984199	150	05/30/1989	SEMICONDUCTOR MEMORY CELLS HAVING COMMON CONTACT HOLE	SATOI SHINI
07364033	5047817	150	06/09/1989	STACKED CAPACITOR FOR SEMICONDUCTOR MEMORY DEVICE	SATOI SHINI
07376662	Not Issued	166	07/07/1989	FIELD SHIELD ISOLATION STRUCTURE FOR SEMICONDUCTOR MEMORY DEVICE AND METHOD FOR MANUFACTURING THE SAME	SATOI SHINI
07377998	5093706	150	07/11/1989	SEMICONDUCTOR DEVICE HAVING MULTIPLE LAYER RESISTANCE LAYER STRUCTURE AND MANUFACTURING METHOD THEREFOR	SATOI SHINI
07391008	5067000	150	08/09/1989	SEMICONDUCTOR DEVICE HAVING FIELD SHIELD ISOLATION	SATOI SHINI
07405284	4994893	150	09/11/1989	FIELD EFFECT TRANSISTOR HAVING SUBSTANTIALLY COPLANAR SURFACE STRUCTURE	SATOI SHINI
07409379	5097310	150	09/19/1989	COMPLEMENTARY SEMICONDUCTOR DEVICE HAVING IMPROVED DEVICE ISOLATING REGION	SATOI SHINI

07421568	Not Issued	163	10/11/1989	SEMICONDUCTOR DEVICE HAVING IMPROVED SOURCE AND DRAIN CONTACT REGIONS AND MANUFACTURING METHOD THEREFOR	SATOI SHINI
07425017	5177571	150	10/23/1989	AN LDD MOSFET WITH PARTICULARLY SHAPED GATE ELECTRODE IMMUNE TO HOT ELECTRON EFFECT	SATOI SHINI
07434692	5051948	250	10/20/1989	CONTENT ADDRESSABLE MEMORY DEVICE	SATOI SHINI
07436998	Not Issued	166	11/15/1989	SEMICONDUCTOR DEVICE HAVING FIELD SHIELD ELEMENT ISOLATING STRUCTURE AND METHOD OF MANUFACTURING THE SAME	SATOI SHINI
07446560	4998161	150	12/05/1989	LDD MOS DEVICE HAVING AN ELEMENT SEPARATION REGION HAVING AN ELECTROSTATIC SCREENING ELECTRODE	SATOI SHINI
07450769	Not Issued	166	II .	SEMICONDUCTOR DEVICE AND METHOD OF MANUFACTURING THE SAME	SATOI SHINI
07473762	5064898	150	02/02/1990	ROOM TEMPERATURE-CURABLE ORGANOPOLYSILOXANE COMPOSITION AND METHOD FOR THE PREPARATION THEREOF	SATOI SHINI(
07475870	5087683	150	02/06/1990	PROCESS FOR PRODUCING ALPHA, BETA - HYDROXYFLUOROALKYLPOLYSILOXANES	SATOI SHINI(
<u>07515416</u>	5124469	150	04/27/1990	ORGANOSILICON COMPOUND	SATOI SHINI
07526943	5049959	150		SEMICONDUCTOR INTEGRATED CIRCUIT DEVICE	SATOI SHINI
07538817	5084752	150	06/15/1990	SEMICONDUCTOR DEVICE HAVING BONDING PAD COMPRISING BUFFER LAYER	SATOI SHINI
07555787	Not Issued	164	07/19/1990	PHOTOCURABLE ORGANOPOLYSILOXANE COMPOSITION	SATOI SHINI
07562318	5126420	150	08/03/1990	RTV ORGANOPOLYSILOXANE COMPOSITIONS	SATOI SHINI
07562320	5101057	150		FLUORINATED CARBOXYLIC ACID DERIVATIVES AND METHODS FOR MAKING	SATOI SHINI
07562321	5194648	150	08/03/1990	FLUORINATED CARBOXYLIC ACID	SATO

				DERIVATIVES AND METHODS FOR MAKING	SHINI
07606276	5094965	150	10/31/1990	FIELD EFFECT TRANSISTOR HAVING SUBSTANTIALLY COPLANAR SURFACE STRUCTURE AND A MANUFACTURING METHOD THEREFOR	SATOI SHINI
07614963	5225704	150		FIELD SHIELD ISOLATION STRUCTURE FOR SEMICONDUCTOR MEMORY DEVICE AND METHOD FOR MANUFACTURING THE SAME	SATOI SHINI
07637434	Not Issued	166	01/04/1991	SEMICONDUCTOR MEMORY DEVICE AND METHOD FOR MANUFACTURING THE SAME	SATOI SHINI
07657261	5164803	250	02/19/1991	CMOS SEMICONDUCTOR DEVICE WITH AN ELEMENT ISOLATING FIELD SHIELD	SATOI SHINI
07661381	5089649	150	04/27/1990	ORGANOSILICON COMPOUND	SATOI SHINI

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Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	0	"efficiently teastable display driving circuit".ti.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 07:19
L2	33	satoh.in. and oki.as.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 07:31
L3	4027517	displa\$4 EL\$4 LED\$4 electroluminescen\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 10:23
L4	2624431	switch\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 07:32
L5	191194	measur\$5 near3 (electric\$5 paramete\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 07:34
L6	403	(3 same 4 same 5).ab.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 07:38
L7	46827	test\$5 near3 (individual\$5 pixel\$4 dot\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 09:08
L8	0	(3 same 4 same 5 same 7).ab.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 07:39
L9	0	((3 same 4 same 5) and 7).ab.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 07:39

L10	8	(3 same 4 same 5 same 7)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 10:24
L13	11232	test\$5 near2 (automatical\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 08:33
L14	3	(3 same 4 same 5 same 13)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 08:27
L15	200	(3 same 4 same 13)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 08:27
L16	37	(3 same 4 same 13).ab.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 08:36
L17	30392	(test\$5 measur\$9) near2 (automatical\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 08:33
L18	511746	(data\$3 signal\$4) same gate\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 08:35
L19	49	(17 same 4 same 18)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 08:40
L20	474	(17 same 4 same 3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 08:40
L21	105	20 and 18	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 08:42

L22	11	20 same 18	US-PGPUB;	OR	OFF	2006/04/12 08:41
122	11	20 Same 10	USPAT; EPO; JPO; DERWENT; IBM_TDB	OK	011	2000/04/12 08.41
L23	19	(3 same 4 same 5 same 17)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 09:06
L24	97366	(test\$5 measur\$8) near3 (individual\$5 pixel\$4 dot\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 09:10
L25	22	(3 same 4 same 5 same 24)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 10:26
L26	128548	(test\$5 measur\$8) near5 (individual\$5 pixel\$4 dot\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 09:14
L27	29	(3 same 4 same 5 same 26)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 09:15
L28	7	27 not 25	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 09:21
L29	198226	(test\$5 measur\$8) with (individual\$5 pixel\$4 dot\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 09:14
L30	45	(3 same 4 same 5 same 29)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 09:15
L31	16	30 not 27	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 09:21

L32	1671645	EL\$4 LED\$4 electroluminescen\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 10:23
L33	1	(32 same 4 same 5 same 7)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 10:25
L34	9	(32 and (4 same 5 same 7))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 10:25
L35	3	(32 same 4 same 5 same 24)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/04/12 10:27